Protected Triac

Silicon Bidirectional Thyristor

Designed for use in solid state relays, MPU interface, TTL logic and other light industrial or consumer applications. Supplied in surface mount package for use in automated manufacturing.

Features

- Sensitive Gate Trigger Current in Two Quadrants
- Blocking Voltage to 600 V
- Surface Mount Package
- Compliant with IEC6100-4-5
- These are Pb-Free Devices

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Note 1) (Sine Wave, 50 to 60 Hz, Gate Open, $T_J = 25$ to $125^{\circ}C$)	V _{DRM,} V _{RRM}	600	V
On–State Current RMS (T _C = 80°C) (Full Sine Wave 50 to 60 Hz)	I _{T(RMS)}	0.8	Α
Peak Non-repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, $T_C = 25^{\circ}C$)	I _{TSM}	8.0	Α
Circuit Fusing Considerations (Pulse Width = 8.3 ms)	I ² t	0.4	A ² s
Peak Gate Power $(T_C = 80^{\circ}C, \text{ Pulse Width } \leq 1.0 \mu\text{s})$	P _{GM}	5.0	W
Average Gate Power (T _C = 80°C, t = 8.3 ms)	P _{G(AV)}	0.1	W
Non-Repetitive Line Peak Voltage (IEC6100-4-5)	V _{PP}	2.0	kV
Critical Rate of Rise of All–State Current ($I_G = 2 \times I_{GT}$, $t_r < 100 \mu s$, $T_J = 1255C$)	di/dt	100	A/μs
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

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PROTECTED TRIAC 0.8 AMPERE RMS 600 VOLTS



MARKING DIAGRAM



SOT-223 CASE 318E



A = Assembly Location

′ = Year

W = Work Week 08106 = Device Code

(Note: Microdot may be in either location)

= Pb-Free Package

PIN ASSIGNMENT				
1	OUT			
2	СОМ			
3	Gate			
4	СОМ			

ORDERING INFORMATION

Device	Package	Shipping [†]
NYE08-10B6ST1G	SOT-223 (Pb-Free)	1000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

THERMAL CHARACTERISTICS

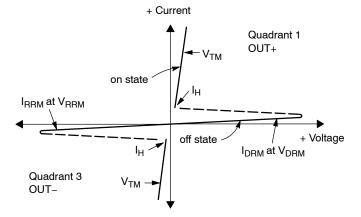
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	50	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	160	°C/W
Maximum Lead Temperature for Soldering Purposes for 10 Seconds	TL	260	°C

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted; Electricals apply in both directions)

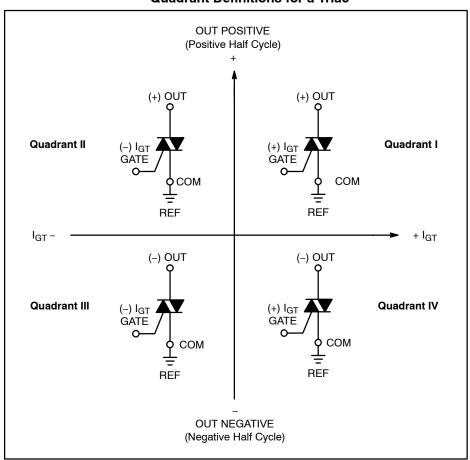
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
$ \begin{array}{ll} \mbox{Peak Repetitive Blocking Current} & T_{J} = 25^{\circ}\mbox{C} \\ \mbox{($V_{D} = V_{DRM}/V_{RRM}$; Gate Open)} & T_{J} = +125^{\circ}\mbox{C} \\ \end{array} $	I _{DRM} , I _{RRM}	- -	- -	2.0 200	μ Α μ Α
ON CHARACTERISTICS					
Peak On–State Voltage ($I_{TM} = \pm 1.1$ A Peak; Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2.0 %)	V _{TM}	=	-	1.3	V
Gate Trigger Current (dc) $ (V_D = 12 \text{ Vdc}, \ R_L = 30 \ \Omega) $ $ \text{OUT(+)}, \ \text{G(-)} $ $ \text{OUT(-)}, \ \text{G(-)} $	I _{GT}	0.15 0.15	- -	10 10	mA
Latching Current (V_D = 12 V, I_G = 1.2 x I_{GT}) OUT(+), G(-) All Types OUT(-), G(-) All Types	ΙL	- -	- -	30 30	mA
Gate Trigger Voltage (dc) (V_D = 12 Vdc, R_L = 30 Ω)	V _{GT}	=	-	1.0	V
Gate Non–Trigger Voltage (V_D = 12 V, R_L = 30 Ω , T_J = 125°C) Quadrants 2, 3	V _{GD}	0.15	-	-	V
Dynamic Resistance	R_D	_	-	300	mΩ
Holding Current (V _D = 12 Vdc, Initiating Current = 50 mA, Gate Open)	I _H	-	-	25	mA
DYNAMIC CHARACTERISTICS					
Rate of Change of Commutating Current (Commutating dv/dt = 15 V/ μ s, Gate Open, T $_J$ = 125°C, f = 250 Hz, without Snubber)	di/dt(c)	0.3	-	-	A/ms
Critical Rate of Rise of Off–State Voltage (V_D = 67% V_{DRM} , Exponential Waveform, Gate Open, T_J = 125°C)	dv/dt	500	-	-	V/μs
Clamping Voltage (I_{CL} = 1.0 mA, t_p = 1 ms, T_J = 125°C)	V_{CL}	650	-	-	٧

Voltage Current Characteristic of Triacs (Bidirectional Device)

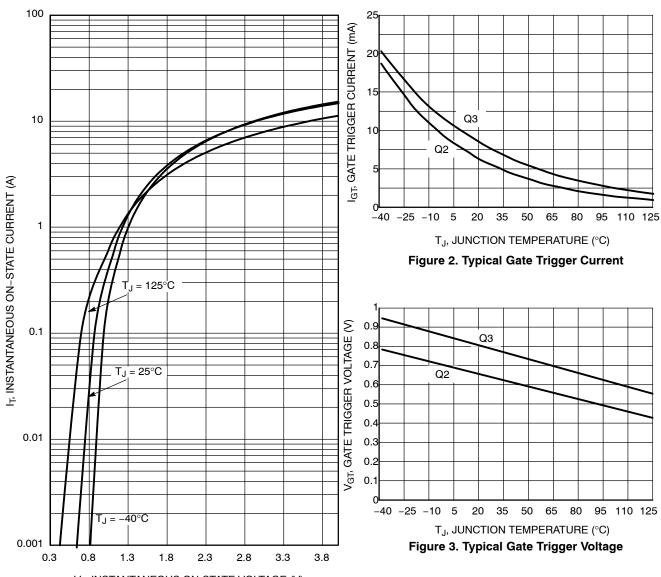
Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
I _H	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to COM.



V_T, INSTANTANEOUS ON-STATE VOLTAGE (V)

Figure 1. Maximum On-State Voltage Characteristics

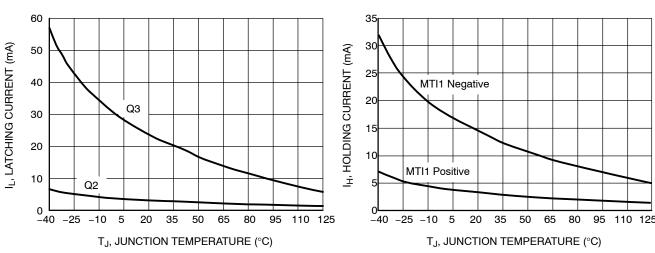
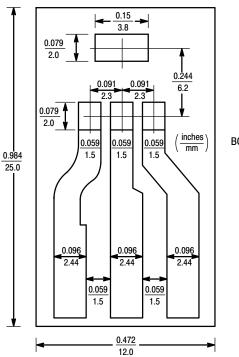


Figure 5. Typical Holding Current

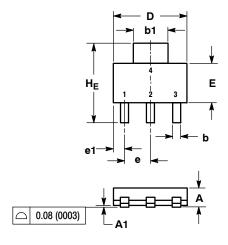


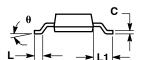
BOARD MOUNTED VERTICALLY IN CINCH 8840 EDGE CONNECTOR. BOARD THICKNESS = 65 MIL., FOIL THICKNESS = 2.5 MIL. MATERIAL: G10 FIBERGLASS BASE EPOXY

Figure 1. PCB for Thermal Impedance and Power Testing of SOT-223

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUE N



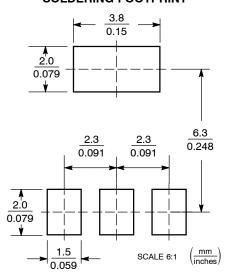


NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
C	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
Е	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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